

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1. (Original) An OLED device comprising a light-emitting layer containing a host and a dopant where the dopant comprises a boron compound containing a bis(azinyl)methene boron complex group.
2. (Original) The device of claim 1 wherein the layer comprises a host and dopant where the dopant is present in an amount of up to 10 wt % of the host.
3. (Original) The device of claim 2 wherein the dopant is present in an amount of 0.1-5.0 wt % of the host.
4. (Original) The device of claim 1 wherein the boron complex group is a 6,6,6-tricyclic bis(azinyl)methene boron complex group.
5. (Original) The device of claim 4 wherein the boron complex group is a bis(pyridinyl)methene boron complex group.
6. (Original) The device of claim 5 wherein at least one of the pyridyl groups is substituted.
7. (Original) The device of claim 6 wherein at least one of the pyridyl groups has substituent groups joined to form a fused ring.
8. (Original) The device of claim 1 wherein the host comprises a chelated oxinoid compound or an anthracene compound.
9. (Original) The device of claim 8 wherein the host comprises a chelated oxinoid compound.
10. (Original) The device of claim 8 wherein the host comprises an anthracene compound.

18. (Currently amended) The device of claim 14 wherein there is present at least one X^a or X^b group selected from the group consisting of halide, ~~and~~ alkyl, aryl, alkoxy, and aryloxy groups.

19. (Currently amended) The device of claim 14 wherein Z^a and Z^b are independently selected from the group consisting of fluorine, ~~and~~ alkyl, aryl, alkoxy and aryloxy groups.

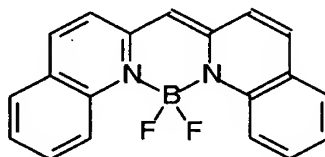
20. (Original) The device of claim 19 wherein Z^a and Z^b are F.

21. (Original) The device of claim 14 wherein the layer comprises a host and dopant where the dopant is present in an amount of up to 10 wt % of the host.

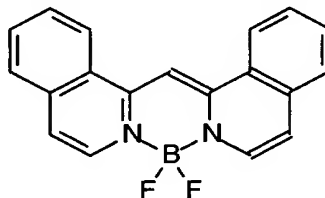
22. (Original) The device of claim 21 wherein the dopant is present in an amount of 0.1-5.0 wt % of the host.

23. (Original) The device of claim 1 wherein the boron compound is selected from the following.

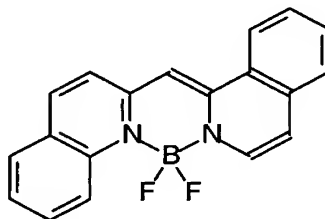
Inv-1



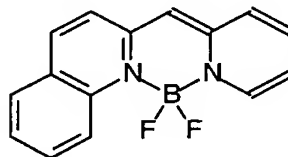
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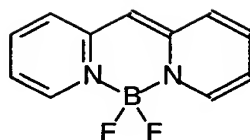
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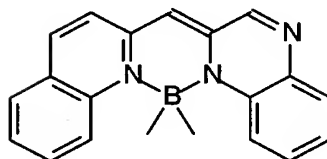
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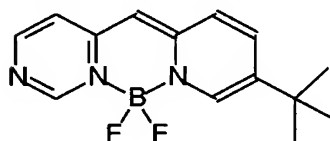
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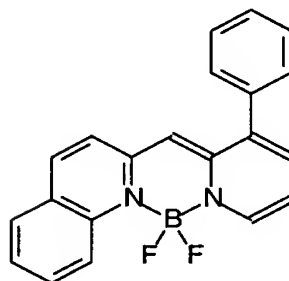
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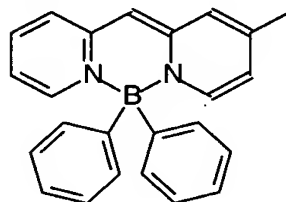
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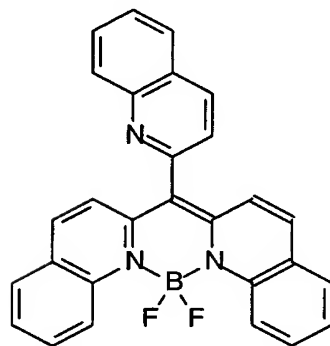
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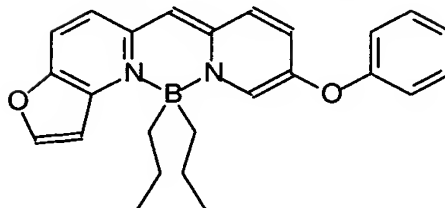
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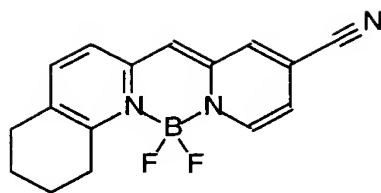
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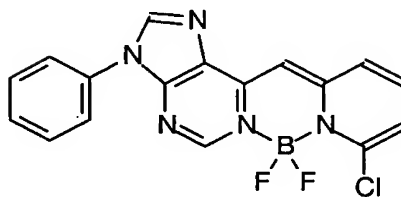
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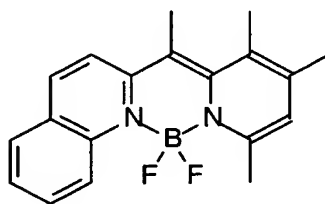
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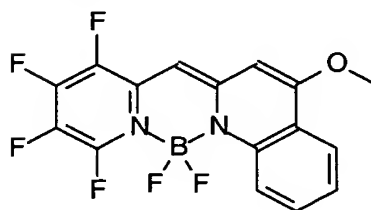
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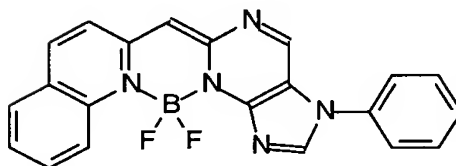
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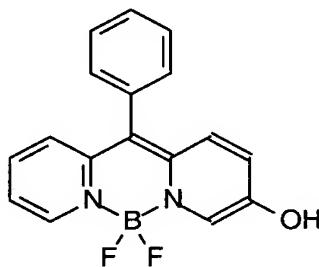
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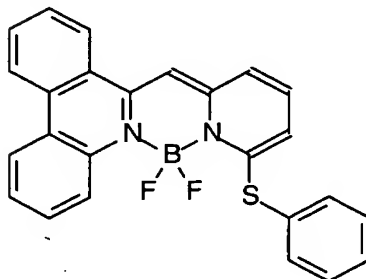
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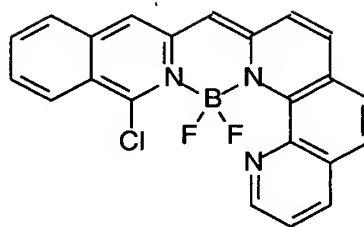
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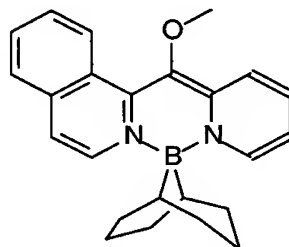
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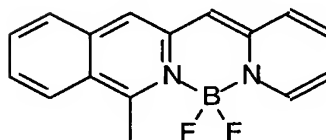
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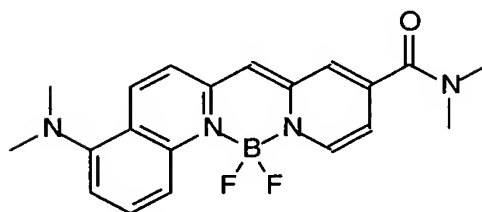
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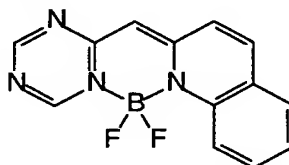
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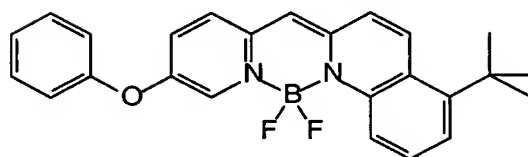
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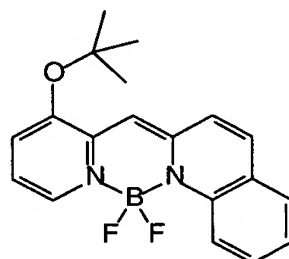
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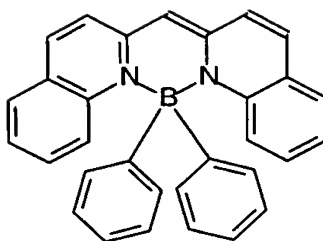
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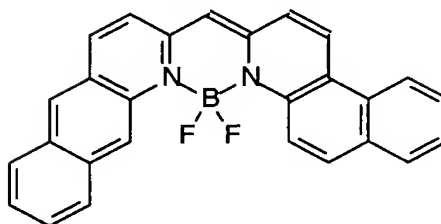
Inv-25



Inv-26

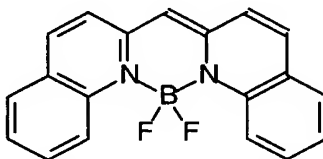


Inv-27

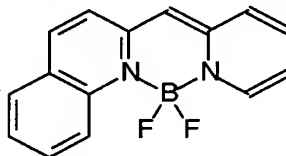


24. (Original) The device of claim 1 wherein the boron compound is selected from the following.

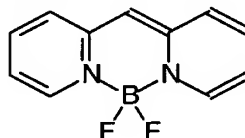
Inv-1



Inv-4



Inv-5



25. (Original) A light emitting device containing the OLED device of claim 1.

26. (Original) A method of emitting light comprising subjecting the device of claim 1 to an applied voltage.